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(54) Mono-, oligo- and polyalkylidenefluorenes and their use as charge transport materials

(57) The invention relates to new conjugated mono-, oligo- and polyalkylidenefluorenes. The invention further relates to methods for their preparation, their use as semiconductors or charge transport materials in optical, electrooptical or electronic devices including field

effect transistors, electroluminescent, photovoltaic and sensor devices. The invention further relates to field effect transistors and semiconducting components comprising the new mono-, oligo- and polymers.

Description

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Field of Invention

[0001] The invention relates to new conjugated mono-, oligo- and polyalkylidenefluorenes. The invention further relates to methods for their preparation, their use as semiconductors or charge transport materials in optical, electrooptical or electronic devices including field effect transistors, electroluminescent, photovoltaic and sensor devices. The invention further relates to field effect transistors and semiconducting components comprising the new mono-, oligo- and polymers.

Background and PriorArt

[0002] Organic materials have recently shown promise as the active layer in organic based thin film transistors and organic field effect transistors [see H. E. Katz, Z. Bao and S. L. Gilat, *Acc. Chem. Res.*, 2001, **34**, 5, 359]. Such devices have potential applications in smart cards, security tags and the switching element in flat panel displays. Organic materials are envisaged to have substantial cost advantages over their silicon analogues if they can be deposited from solution, as this enables a fast, large-area fabrication route.

[0003] The performance of the device is principally based upon the charge carrier mobility of the semiconducting material and the current on/off ratio, so the ideal semiconductor should have a low conductivity in the off state, combined with a high charge carrier mobility (> 1 x 10⁻³ cm² V⁻¹ s⁻¹). In addition, it is important that the semiconducting material is relatively stable to oxidation i.e. it has a high ionisation potential, as oxidation leads to reduced device performance. [0004] A known compound which has been shown to be an effective p-type semiconductor for OFETs is pentacene [see S. F. Nelson, Y. Y. Lin, D. J. Gundlach and T. N. Jackson, *Appl. Phys. Lett.*, 1998, 72, 1854].

[0005] When deposited as a thin film by vacuum deposition, it was shown to have carrier mobilities in excess of 1 cm² V⁻¹ s⁻¹ with very high current on/off ratios greater than 10⁶. However, vacuum deposition is an expensive processing technique that is unsuitable for the fabrication of large-area films.

[0006] Regular poly(3-hexylthiophene) has been reported with charge carrier mobility between 1 x 10⁻⁵ and 4.5 x 10⁻² cm² V⁻¹ s⁻¹, but with a rather low current on/off ratio between 10 and 10³ [see Z. Bao et al., *Appl. Pys. Lett.* 1997, **78**, 2184]. In general, poly(3-alkylthiophenes) show improved solubility and are able to be solution processed to fabricate large area films. However, poly(3-alkylthiophenes) have relatively low ionisation potentials and are susceptible to doping in air [see H. Sirringhaus et al., *Adv. Solid State Phys.* 1999, **39**, 101].

[0007] It is the aim of the present invention to provide new materials for use as semiconductors or charge transport materials, which are easy to synthesize, have high charge mobility, good processibility and improved oxidative stability. Other aims of the invention are immediately evident to those skilled in the art from the following description.

[0008] The inventors have found that these aims can be achieved by providing new monomers, oligomers and polymers based on 9-alkylidenefluorene (1). Poly(9-alkylidenefluorenes) (2) exhibit a high degree of planarity in the backbone due to the carbon sp² hybridisation at the 9 position, in comparison with for example poly(9,9-dialkylfluorenes), and strong interchain pi-pi-stacking interactions making them effective charge transport materials with high carrier mobilities. In addition, the high resonance stability of the fused phenylene structure leads to a high ionisation potential and hence good stability. Also, the incorporation of alkyl substitutents R¹, R² into the alkylidenefluorene group leads to good solubility and thus good solution processibility of the materials according to the present invention. Solution processing during device manufacture has the advantage over vaccum deposition of being a potentially cheaper and faster technique.

[0009] The synthesis of polyfluorenes and poly(9,9-dialkylfluorenes) for use in light emitting diodes have been reported in prior art, for example in US 6,169,163. Furthermore, US 6,169,163 discloses monosubstituted 9-alkylidene-

fluorenes (1) and poly(9-alkylidenefluorenes) (2) (R^1 = alkyl, R^2 = H). Copolymers of disubstituted 9-alkylidenefluorenes (R^1 = R^2 = alkyl optionally substituted) are disclosed in WO 00/46321, although no examples or method for the preparation of monomer 1 is disclosed. The synthesis of specific monosubstituted 9-alkylidenefluorenes (1) (R^1 = alkyl, R^2 = H) is also described in K. Subba Reddy et al., *Synthesis*, 2000,1, 165. The synthesis of specific disubstituted 9-alkylidenefluorenes (1) (R^1 = methyl, R^2 = methyl or phenyl) is disclosed in K. C. Gupta et al., *Indian J. Chem., Sect. B*, 1986, 25B, 1067. The synthesis of a specific copolymer of disubstituted 9-alkylidenefluorene (1) (R^1 = methyl, R^2 = ethyl) is reported by M.Ranger and M. Leclerc, *Macromolecules* 1999, 32, 3306. These two methods are not readily amenable to the preparation of molecules with alkyl chains larger than propyl. Moreover, polymers of unsymmetrical 9-alkylidenefluorenes have the general problem of poor regioregularity and therefore poor ordering and packing in the solid state. Mono- and poly(9-alkylidenefluorenes) according to the present invention have not been reported.

[0010] A further aspect of the invention relates to reactive mesogens consisting of a central core comprising one or more 9-alkylidenefluorene units, and optionally comprising further unsaturated organic groups that form a conjugated system together with the 9-alkylidenefluorene units, said core being linked, optionally via a spacer group, to one or two polymerisable groups. The reactive mesogens can induce or enhance liquid crystal phases or are liquid crystalline themselves. They can be oriented in their mesophase and the polymerisable group can be polymerised or crosslinked in situ to form polymer films with a high degree of order, thus yielding improved semiconductor materials with high stability and high charge carrier mobility.

[0011] Grell et al., J. Korean Phys. Soc. 2000, 36(6), 331 suggest a reactive mesogen comprising a conjugated distyrylbenzene core with two reactive acrylate end groups as a model compound for molecular electronics. However, there is no disclosure of reactive mesogens of 9-alkylidenefluorene.

[0012] A further aspect of the invention relates to liquid crystal polymers, in particular liquid crystal side chain polymers obtained from the reactive mesogens according to the present invention, which are then further processed e.g. from solution as thin layers for use in semiconductor devices.

25 Definition of Terms

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[0013] The terms 'liquid crystalline or mesogenic material' or 'liquid crystalline or mesogenic compound' means materials or compounds comprising one or more rod-shaped, lath-shaped or disk-shaped mesogenic groups, i.e. groups with the ability to induce liquid crystal phase behaviour. The compounds or materials comprising mesogenic groups do not necessarily have to exhibit a liquid crystal phase themselves. It is also possible that they show liquid crystal phase behaviour only in mixtures with other compounds, or when the mesogenic compounds or materials, or the mixtures thereof, are polymerised.

[0014] The term 'polymerisable' includes compounds or groups that are capable of participating in a polymerisation reaction, like radicalic or ionic chain polymerisation, polyaddition or polycondensation, and reactive compounds or reactive groups that are capable of being grafted for example by condensation or addition to a polymer backbone in a polymeranaloguous reaction.

[0015] The term 'film' includes self-supporting, i.e. free-standing, films that show more or less pronounced mechanical stability and flexibility, as well as coatings or layers on a supporting substrate or between two substrates.

40 Summary of the Invention

[0016] The invention relates to mono-, oligo- and polymers of formula I

 $R^9 - [(A)_a - (B)_b - (C)_a]_a - R^{10}$

wherein

A and C are independently of each other -CX1=CX2-, -C=C-, or optionally substituted arylene or heteroarylene,

X1 and X2 are independently of each other H, F, Cl or CN,

B is a group of formula II

are independently of each other halogen, straight chain, branched or cyclic alkyl with 1 to 20 C-atoms, which may be unsubstituted, mono- or poly-substituted by F, Cl, Br, I or CN, it being also possible for one or more nonadjacent CH₂ groups to be replaced, in each case independently from one another, by -O-, -S-, -NH-, -NR°-, -SiR⁰R⁰0-, -CO-, -COO-, -COO-, -COO-, -SO₂-, -S- CO-, -CO-S-, -CH=CH- or -C≡C- in such a manner that O and/or S atoms are not linked directly to one another, optionally substituted aryl or heteroaryl, or P-Sp-X,

R³ to R¹⁰ are independently of each other H or have one of the meanings given for R¹,

R⁰ and R⁰⁰ are independently of each other H or alkyl with 1 to 12 C-atoms,

P is a polymerisable or reactive group,

Sp is a spacer group or a single bond, and

30 X is -0-, -S-, -OCH₂-, -CH₂O-, -CO-, -OCO-, -OCO-O-, -CO-NR⁰-, -NR⁰-CO-, -OCH₂-, -CH₂O-, -SCH₂-, -CH₂S-, -CH=CH-COO-, -OOC-CH=CH- or a single bond,

a, b and c are independently of each other 0 or 1, with a + b + C > 0, and wherein in at least one recurring unit $[(A)_a - (B)_b - (C)_c]$ b is 1, and

n is an integer ≥ 1,

wherein the recurring units $[(A)_{a^{-}}(B)_{b^{-}}(C)_{c}]$ can be identical or different, and with the provisos that

a) in case n is 1, a and c are 0, R³⁻⁸ are H, and one of R¹ and R² is methyl and the other is methyl, ethyl or phenyl, R⁹ and R¹⁰ are not at the same time Cl or Br, and

b) A and C are different from 2,7-(4-hexylphenyl)fluorene-9-carbonyl.

45 [0017] The invention further relates to a process of preparing monomers of formula I wherein n is 1, very preferably monomers of formula II-1

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wherein R¹ to R¹⁰ are as defined above, in particular wherein R⁹ and R¹⁰ are independently of each other halogen.

[0018] The invention further relates to the use of mono-, oligo- and polymers according to the invention as semiconductors or charge transport materials, in particular in optical, electrooptical or electronic devices, like for example components of integrated circuitry, field effect transistors (FET) for example as thin film transistors in flat panel display applications or for Radio Frequency Identification (RFID) tags, or in semiconducting components for organic light emitting diode (OLED) applications such as electroluminescent displays or backlights of e.g. liquid crystal displays, for photovoltaic or sensor devices, as electrode materials in batteries, as photoconductors and for electrophotographic applications like electrophotographic recording.

[0019] The invention further relates to a field effect transistor, for example as a component of integrated circuitry, as a thin film transistor in flat panel display applications, or in a Radio Frequency Identification (RFID) tag, comprising one or more mono-, oligo- or polymers according to the invention.

[0020] The invention further relates to a semiconducting component, for example in OLED applications like electroluminescent displays or backlights of e.g. liquid crystal displays, in photovoltaic or sensor devices, as electrode materials in batteries, as photoconductors and for electrophotographic applications, comprising one or more mono-, oligoor polymers according to the invention.

[0021] The invention further relates to a security marking or device comprising an RFID or ID tag or a FET according to the invention.

Detailed Description of the Invention

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[0022] The mono-, oligo- and polymers according to the present invention are especially useful as charge transport semiconductors in that they have high carrier mobilities. Particularly preferred are mono-, oligo- and polymers wherein the group B is substituted by one or more alkyl, thioalkyl or fluoroalkyl groups. The introduction of alkyl, thioalkyl and fluoroalkyl side chains to the group B improves the solubility and therefore the solution processibility of the inventive materials. Furthermore, the presence of fluoroalkyl side chains also renders the inventive materials effective as n-type semiconductors.

40 [0023] Particularly preferred are mono-, oligo- and polymers comprising at least one group of formula I and at least one reactive group that is capable of a polymerisation or crosslinking reaction.

[0024] Further preferred are mono-, oligo- and polymers comprising at least one group of formula I that are mesogenic or liquid crystalline, in particular polymers of formula I forming calamitic phases, and reactive mesogens of formula I, comprising one or more groups P-Sp-X, forming calamitic phases.

[0025] In the oligo- and polymers of the present invention the recurring units (A)_a-(B)_b-(C)_c in case of multiple occurrence can be selected of formula I independently of each other, so that an oligo- or polymer may comprise identical or different recurring units (A)_a-(B)_b-(C)_c. The oligo- and polymers thus include homopolymers and copolymers like for example

- statistically random copolymers, for example with a monomer sequence such as -A-B-C-C-B-A-B-,
- alternating copolymers, for example with a monomer sequence such as -A-B-C-A-B-C-, and
- block copolymers, for example with a monomer sequence such as -A-A-B-B-B-B-C-C-C-, wherein the groups A and C preferably form a conjugated system together with the group B.

[0026] Further preferred are mono-, oligo- and polymers comprising one or more recurring units $(A)_a$ - $(B)_b$ - $(C)_c$, wherein a=c=0 and b=1, very preferably consisting exclusively of such recurring units.

[0027] Further preferred are mono-, oligo- and polymers comprising one or more recurring units $(A)_a$ - $(B)_b$ - $(C)_c$, wherein b = c = 1 and a = 0, very preferably consisting exclusively of such recurring units.

[0028] Further preferred are mono-, oligo- and polymers comprising one or more recurring units $(A)_a$ - $(B)_b$ - $(C)_c$, wherein a = b = c = 1, very preferably consisting exclusively of such recurring units.

- 5 [0029] Further preferred are mono-, oligo- and polymers of formula I wherein
 - n is an integer from 1 to 5000,
 - n is an integer from 2 to 5000, in particular from 20 to 1000,
 - n is an integer from 2 to 5,

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- n is 2 and one or both of R9 and R10 denote P-Sp-X,
- 15 n is an integer from 1 to 15 and one or both of R9 and R10 denote P-Sp-X,
 - n is an integer from 2 to 5000 and R⁹ and R¹⁰ have one of the meanings of formula I different from P-Sp-X,
 - the molecular weight is from 5000 to 100000,
 - R1 and R2 are identical,
 - R¹ and R² are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkenyl, C₁-C₂₀-alkyl, or optionally substituted aryl or heteroaryl, in particular C₁-C₂₀-alkyl or C₁-C₂₀-fluoroalkyl,
 - R¹ and R² are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkynyl, C₁-C₂₀-alkoxy, C₁-C₂₀-thioalkyl, C₁-C₂₀-silyl, C₁-C₂₀-ester, C₁-C₂₀-amino, C₁-C₂₀-fluoroalkyl, or optionally substituted aryl or heteroaryl, in particular C₁-C₂₀-alkyl or C₁-C₂₀-fluoroalkyl, and R³ to R³ are H,
 - R³ to R⁸ are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkynyl, C₁-C₂₀-alkoxy, C₁-C₂₀-thioalkyl, C₁-C₂₀-silyl, C₁-C₂₀-ester, C₁-C₂₀-amino, C₁-C₂₀-fluoroalkyl, and optionally substituted aryl or heteroaryl,
- R⁹ and R¹⁰ are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkoxy, C₁-C₂₀-thioalkyl, C₁-C₂₀-silyl, C₁-C₂₀-ester, C₁-C₂₀-amino, C₁-C₂₀-fluoroalkyl, and optionally substituted aryl or heteroaryl,
 - A and C are optionally substituted arylene or heteroarylene,
 - A and C are -CX1=CX2- or -C≡C-,
 - in at least one monomer unit (A)_a-(B)_b-(C)_c a, b and c are 1, and one of A and C is arylene or heteroarylene and the other is - CX¹=CX²- or -C≡C-,
 - n>1.

[0030] Especially preferred are mono-, oligo- and polymers of the following formulae

$$R^{9}$$
 R^{9}
 R^{10}
 R^{10}
 R^{10}

$$R^{9}$$
 R^{8}
 R^{7}
 R^{6}
 R^{5}
 R^{6}
 R^{7}
 R^{6}
 R^{7}
 R^{6}
 R^{7}
 R^{6}
 R^{7}
 R^{8}
 R^{10}
 R^{10}
 R^{10}

$$R^{8}$$
 R^{1}
 R^{2}
 R^{3}
 R^{4}
 R^{5}
 R^{6}
 R^{7}
 R^{6}
 R^{6}
 R^{6}
 R^{7}
 R^{6}
 R^{7}
 R^{8}
 R^{10}
 R^{10}
 R^{10}

$$R^{8}$$
 R^{9}
 R^{9}
 R^{6}
 R^{6}
 R^{6}
 R^{6}
 R^{6}
 R^{6}
 R^{7}
 R^{10}

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wherein R¹ to R¹⁰ have the meanings given above, Ar is arylene or heteroarylene, and n is an integer from 1 to 5000. [0031] Particularly preferred are oligo- and polymers of these preferred formulae wherein R¹ and R² are independently of each other alkyl or thioalkyl with 1-16 C-atoms that are optionally fluorinated, R³ to R⁸ are independently of each other H, F or alkyl with 1-16 C atoms that is optionally fluorinated, R⁹ and R¹⁰ are independently of each other H, halogen, alkyl with 1-16 C atoms that is optionally fluorinated or P-Sp-X, Ar is 1,4-phenylene, alkoxyphenylene, alkylfluorene, thiophene-2,5-diyl, thienothiophene-2,5-diyl or dithienothiophene-2,6-diyl, and n is an integer from 2 to 5000, in particular from 20 to 1000.

[0032] Further preferred are reactive monomers of the above preferred formulae, wherein n is 2, R¹ and R² are independently of each other alkyl with 1-16 C atoms that is optionally fluorinated, R³ to R³ are independently of each other H, F or alkyl or thioalkyl with 1-16 C atoms that are optionally fluorinated, R³ and R¹0 are independently of each other H, halogen, alkyl with 1-16 C atoms that is optionally fluorinated or P-Sp-X, Ar is 1,4-phenylene, alkoxyphenylene, alkylfluorene, thiophene-2,5-diyl, thienothiophene-2,5-diyl or dithienothiophene-2,6-diyl, with at least one, preferably both of R³ and R¹0 denoting P-Sp-X.

[0033] Aryl and heteroaryl preferably denote a mono-, bi- or tricyclic aromatic or heteroaromatic group with up to 25 C atoms that may also comprise condensed rings and is optionally substituted with one or more groups R1 as defined in formula I.

[0034] Especially preferred aryl and heteroaryl groups are phenyl in which, in addition, one or more CH groups may be replaced by N, naphthalene, thiophene, thienothiophene, dithienothiophene, alkyl fluorene and oxazole, all of which can be unsubstituted, mono- or polysubstituted with L, wherein L is halogen or an alkyl, alkoxy, alkylcarbonyl or alkoxycarbonyl group with 1 to 12 C atoms, wherein one or more H atoms may be replaced by F or Cl.

35 [0035] Arylene and heteroarylene preferably denote a bivalent mono-, bi- or tricyclic aromatic or heteroaromatic group with up to 25 C atoms that may also comprise condensed rings and is optionally substituted with one or more groups R1.

[0036] Especially preferred arylene and heteroarylene groups are 1,4-phenylene in which, in addition, one or more CH groups may be replaced by N, naphthalene-2,6-diyl, thiophene-2,5-diyl, thienothiophene-2,5-diyl, dithienothiophene-2,6-diyl, alkyl fluorene and oxazole, all of which can be unsubstituted, mono- or polysubstituted with L as defined above.

[0037] CX1=CX2 is preferably -CH=CH-, -CH=CF-, -CF=CH-, -CF=CF-, - CH=C(CN)- or -C(CN)=CH-.

[0038] If in the formulae shown above and below one of R^1 to R^{10} is an alkyl or alkoxy radical, i.e. where the terminal CH_2 group is replaced by - O-, this may be straight-chain or branched. It is preferably straight-chain, has 2 to 8 carbon atoms and accordingly is preferably ethyl, propyl, butyl, pentyl, hexyl, heptyl, octyl, ethoxy, propoxy, butoxy, pentoxy, hexyloxy, heptoxy, or octoxy, furthermore methyl, nonyl, decyl, undecyl, dodecyl, tridecyl, tetradecyl, pentadecyl, nonoxy, decoxy, undecoxy, dodecoxy, tridecoxy or tetradecoxy, for example.

[0039] Oxaalkyl, i.e. where one CH_2 group is replaced by -O-, is preferably straight-chain 2-oxapropyl (=methoxymethyl), 2- (=ethoxymethyl) or 3-oxabutyl (=2-methoxyethyl), 2-, 3-, or 4-oxapentyl, 2-, 3-, 4-, or 5-oxahexyl, 2-, 3-, 4-, 5-, 6- or 7-oxaoctyl, 2-, 3-, 4-, 5-, 6-, 7- or 8-oxanonyl or 2-, 3-, 4-, 5-, 6-, 7-, 8- or 9-oxadecyl, for example.

[0040] Thioalkyl, I.e where one CH_2 group is replaced by -S-, is preferably straight-chain thiomethyl (-SCH₃), 1-thioethyl (-SCH₂CH₃), 1-thiopropyl (= -SCH₂CH₂CH₃), 1-(thiobutyl), 1-(thiopentyl), 1-(thiohexyl), 1-(thiohexyl), 1-(thiohexyl), 1-(thiodecyl), 1-(thiodecyl), 1-(thiodecyl), wherein preferably the CH_2 group adjacent to the sp² hybridised vinyl carbon atom is replaced.

[0041] Fluoroalkyl is preferably C_iF_{2i+1} , wherein i is an integer from 1 to 15, in particular CF_3 , C_2F_5 , C_3F_7 , C_4F_9 , C_5F_{11} , C_6F_{13} , C_7F_{15} or C_8F_{17} , very preferably C_6F_{13} .

[0042] Halogen is preferably F, Br or Cl.

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[0043] The polymerisable or reactive group P is preferably selected from CH₂=CW¹-COO-,

$$W^2HC \longrightarrow CH - W^2 \longrightarrow (CH_2)_k - O$$

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[0045] Very preferred are acrylate and oxetane groups. Oxetanes produce less shrinkage upon polymerisation (cross-linking), which results in less stress development within films, leading to higher retention of ordering and fewer defects. Oxetane cross-linking also requires cationic initiator, which unlike free radical initiator is inert to oxygen.

[0046] As for the spacer group Sp all groups can be used that are known for this purpose to those skilled in the art. The spacer group Sp is preferably a linear or branched alkylene group having 1 to 20 C atoms, in particular 1 to 12 C atoms, in which, in addition, one or more non-adjacent CH₂ groups may be replaced by -O-, -S-, -NH-, - N(CH₃)-, -CO-, -O-CO-, -S-CO-, -O-COO-, -CO-S-, -CO-O-,-CH(halogen)-, -C(halogen)₂, -CH(CN)-, -CH=CH- or -C=C-, or a siloxane group.

[0047] Typical spacer groups are for example - $(CH_2)_p$ -, - $(CH_2CH_2O)_r$ - CH_2CH_2 -, - CH_2CH_2 -, - CH_2CH_2 - or - CH_2CH_2 - or - $(SiR^0R^{00}-O)_p$ -, with p being an integer from 2 to 12, r being an integer from 1 to 3 and R° and R°0 having the meanings given in formula I.

[0048] Preferred spacer groups are ethylene, propylene, butylene, pentylene, hexylene, heptylene, octylene, nonylene, decylene, undecylene, dodecylene, octadecylene, ethyleneoxyethylene, methyleneoxybutylene, ethylenethioethylene, ethylene-N-methyl-iminoethylene, 1-methylalkylene, ethenylene, propenylene and butenylene for example.

[0049] Further preferred are compounds with one or two groups P-Sp-X wherein Sp and/or X is a single bond.

[0050] In case of compounds with two groups P-Sp-X, each of the two polymerisable groups P, the two spacer groups Sp, and the two linkage groups X can be identical or different.

[0051] SCLCPs obtained from the inventive compounds or mixtures by polymerisation or copolymerisation have a backbone that is formed by the polymerisable group P in formula I.

[0052] The mono-, oligo- and polymers of the present invention can be synthesized according to or in analogy to known methods. Some preferred methods are described below.

[0053] Starting from the commercially available 2,7-dibromofluorene, a synthetic route to 2,7-dibromo-9-alkylidene-fluorene monomers (2) is outlined below in Scheme 1. 2,7-Dibromofluorene(3) is oxidised with potassium permanganate and copper sulfate in the solid state to afford 2,7-dibromofluorenone (4) in 80%. This method avoids the use of toxic and carcinogenic chromium salts. Dibromofluorenone (4) is reacted with carbon tetrabromide and triphenylphosphine under Corey-Fuchs conditions to afford key intermediate (5). Tetrabromofluorenone (5) reacts with thiols in the presence of base and nickel catalyst to afford dithioalkyl substituted fluorene (6) This can be further reacted with alkyl or aryl Grignard reagents to afford dialkyl or diaryl substituted fluorenone (7) in good yield. Alternatively tetrabromofluorenone (5) can be reacted with 2 equivalents of an alkylzinc reagent in the presence of a palladium catalyst to afford

- (7). Both methods allow the introduction of alkyl chains not readily incorporated by other methods. Tetrabromofluorenone (5) can be reacted with 2 equivalents of aryl boronic acids under Suzuki conditions to afford diaryl substituted fluorenones (8). Reaction of (5) with 2 equivalents of an alkyne under Sonogashira conditions affords dialkynyl substituted fluorenone (9).
- [0054] Attempts to synthesise dialkyl fluorenone (7) by the methods known form prior art as outlined in US 6,169,163 and WO 00/46321, namely the base catalysed reaction of 2,7-dibromofluorene with a dialkyl ketone (eg 4-heptanone) were unsuccessful, no product being obtained.

Scheme 1:

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[0055] An alternative synthesis of dithioalkyl substituted fluorene (6) is outlined in Scheme 2. 2,7-Dibromofluorene is reacted with a base in the presence of carbon disulfide, followed by addition of an alkylating agent. This affords dithioalkyl substituted fluorenes in a one-pot procedure in good yield.

Scheme 2:

[0056] Poly(9-alkylidenefluorenes) (2) are synthesised from the respective dibromofluorene monomers (1) by one of three methods (scheme 3) Firstly, direct polymerisation using Ni(cod)₂ and 2,2'-bipyridine (Yamamoto coupling) to afford (2) [see T. Yamamoto, A. Morita, Y. Miyazaki, T. Maruyama, H. Wakayama, Z. H. Zhou, Y. Nakamura, T. Kanbara, S. Sasaki and K. Kubota, *Macromolecules*, 1992, 25, 1214]. Alternatively, polymerisation using nickel chloride, 2,2'-bipyridine (bpy), triphenylphosphine and zinc to yield (2). Finally the 2,7-dibromofluorene monomer is converted to a monoboronic ester (10) and polymerised under Suzuki conditions [see N. Miyaura, T. Yanagi and A. Suzuki, *Synth. Commun.*, 1981, 11, 513]. Conversion to the mono-boronate ester can be achieved in one step using bis(pinacolato) diboron and a transition metal catalyst [see T. Ishiyama, K. Ishida and N. Miyaura, *Tetrahedron*, 2001, 57, 9813.]. Alternatively halogen lithium exchange at low temperature, followed by quenching with trimethylborate and esterification with pinacol also affords the monoboronic ester.

Scheme 3:

[0057] Other coupling routes to the polymer (2) are Stille coupling [see D. Milstein and J. K. Stille, J. Am. Chem. Soc., 1979, 101, 4992], Rieke coupling [see T.-A. Chen and R. D. Rieke, J. Am. Chem. Soc., 1992, 114, 10087], and Grignard cross-coupling [see Loewe, R.S., S.M. Khersonsky, and R.D. McCullough, Advanced Materials, 1999. 11(3), 250-253; Loewe, R.S., et al., Macromolecules, 2001, 34, 4324-4337.].

Reactive mesogens

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[0058] Compounds of formula I comprising polymerisable groups can be synthesized according to or in analogy to the following methods.

[0059] As shown in Scheme 4, Dibromo 9-alkylidenefluorene (1) can be cross-coupled with an alkyl zinc reagent in the presence of a nickel catalyst to yield (11) [see B. H. Lipshutz, P. A. Blomgren and S. K. Kim, *Tetrahedron Lett.*, 1999, 40, 2, 197]. Many organozinc reagents are commercially available or are readily prepared form the corresponding alkyl iodide. Routine methodology converts the bis-alkyl alcohol or chloride (11) into the bis-acrylate or bis- oxetane.

Scheme 4:

wherein m is an integer e.g. from 1 to 20 and P is a protecting group.

[0060] Polymerisation of reactive mesogens can be carried out for example by thermal cross-linking or photoinitiated cross-linking.

Polymers containing conjugated groups C≡C, CX¹=CX² or Ar

[0061] The Stille coupling of dibromo 9-alkylidenefluorene (6) with the bis-organotin reagent (12) or (13) as shown in Scheme 5 yields polymer (14) containing CX¹=CX² groups or polymer (15) containg C≡C bonds [see R. S. Loewe and R. D. McCullough, *Chem. Mater.*, 2000, 12, 3214.].

Scheme 5:

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SnBu₃

$$X^2$$
 X^1
 X^2
 X^1
 X^2
 X^2
 X^1
 X^2
 $X^$

[0062] The Suzuki coupling of dibromo 9-alkylidenefluorene (1) with bis-boronic acid or ester (14) according to Scheme 6 yields polymer (18) containing aryl groups. Alternatively the bis-boronic acid ester of (1) is synthesised as described above (scheme 1) to afford (17) and this is reacted with a dibromo- or diiodo-arylene group to afford polymer (18)

Scheme 6:

Br
$$R^{1}$$
 R^{2} R^{2} R^{1} R^{2} R

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A further aspect of the invention relates to both the oxidised and reduced form of the compounds and materials according to this invention. Either loss or gain of electrons results in formation of a highly delocalised ionic form, which is of high conductivity. This can occur on exposure to common dopants. Suitable dopants and methods of doping are known to those skilled in the art, e.g. from EP 0 528 662, US 5,198,153 or WO 96/21659.

[0063] The doping process typically implies treatment of the semiconductor material with an oxidating or reducing agent in a redox reaction to form delocalised ionic centres in the material, with the corresponding counterions derived from the applied dopants. Suitable doping methods comprise for example exposure to a doping vapor in the atmospheric pressure or at a reduced pressure, electrochemical doping in a solution containing a dopant, bringing a dopant into contact with the semiconductor material to be thermally diffused, and ion-implantantion of the dopant into the semiconductor material.

[0064] When electrons are used as carriers, suitable dopants are for example halogens (e.g. I₂, Cl₂, Br₂, ICI, ICI₃, IBr and IF), Lewis acids (e.g. PF₅, AsF₅, SbF₅, BF₃, BCI₃, SbCI₅, BBr₃ and SO₃), protonic acids, organic acids, or amino acids (e.g. HF, HCI, HNO₃, H₂SO₄, HCIO₄, FSO₃H and CISO₃H), transition metal compounds (e.g. FeCI₃, FeOCI, Fe(CIO₄)₃, Fe(4-CH₃C₆H₄SO₃)₃, TiCI₄, ZrCI₄, HfCI₄, NbF₅, NbCI₅, TaCI₅, MoF₅, MoCI₅, WF₅, WCI₆, UF₆ and LnCI₃ (wherein Ln is a lanthanoid), anions (e.g. Cl⁻, Br, I⁻, I₃⁻, HSO₄⁻, SO₄²⁻, NO₃⁻, CIO₄⁻, BF₄⁻, PF₆⁻, AsF₆⁻, SbF₆⁻, FeCI₄⁻, Fe(CN)₆⁻³, and anions of various sulfonic acids, such as aryl-SO₃⁻). When holes are used as carriers, examples of dopants are cations (e.g. H⁺, Li⁺, Na⁺, K⁺, Rb⁺ and Cs⁺),

[0065] alkali metals (e.g., Li, Na, K, Rb, and Cs), alkaline-earth metals (e.g., Ca, Sr, and Br), O_2 , XeOF₄, (NO₂+) (SbF₆-), (NO₂+) (SbCl₆-), (NO₂+) (BF₄-), AgClO₄, H₂IrCl₆, La(NO₃)₃ 6H₂O, FSO₂OOSO₂F, Eu, acetylcholine, R₄N+, (R is an alkyl group), R₄P+ (R is an alkyl group), R₆As+ (R is an alkyl group), and R₃S+ (R is an alkyl group).

[0066] The conducting form of the compounds and materials of the present invention can be used as an organic "metal" in applications, for example, but not limited to, charge injection layers and ITO planarising layers in organic light emitting diode applications, films for flat panel displays and touch screens, antistatic films, printed conductive substrates, patterns of tracts in electronic applications such as printed circuit boards and condensers.

[0067] A preferred embodiment of the present invention relates to mono-, oligo- and polymers of formula I that are mesogenic or liquid crystalline, and very preferably comprise one or more polymerisable groups. Very preferred materials of this type are monomers and oligomers of formula I wherein n is an integer from 1 to 15 and R⁹ and/or R¹⁰ denote P-Sp-X.

[0068] These materials are particularly useful as semiconductors or charge transport materials, as they can be aligned into uniform highly ordered orientation in their liquid crystal phase by known techniques, thus exhibiting a higher degree of order that leads to particularly high charge carrier mobility. The highly ordered liquid crystal state can be fixed by in situ polymerisation or crosslinking via the groups P to yield polymer films with high charge carrier mobility and high thermal, mechanical and chemical stability.

[0069] It is also possible to copolymerise the polymerisable mono-, oligo- and polymers according to the present invention with other polymerisable mesogenic or liquid crystal monomers that are known from prior art, in order to induce or enhance liquid crystal phase behaviour.

[0070] Thus, another aspect of the invention relates to a polymerisable liquid crystal material comprising one or more mono-, oligo- or polymers of the present invention as described above and below comprising at least one polymerisable group, and optionally comprising one or more further polymerisable compounds, wherein at least one of the polymerisable mono-, oligo- and polymers of the present invention and/or the further polymerisable compounds is mesogenic or liquid crystalline.

[0071] Particularly preferred are liquid crystal materials having a nematic and/or smectic phase. For FET applications smectic materials are especially preferred. For OLED applications nematic or smectic materials are especially preferred.

[0072] Another aspect of the present invention relates to an anisotropic polymer film with charge transport properties

obtainable from a polymerisable liquid crystal material as defined above that is aligned in its liquid crystal phase into macroscopically uniform orientation and polymerised or crosslinked to fix the oriented state.

[0073] Another aspect of the invention relates to a liquid crystal side chain polymer (SCLCP) obtained from a polymerisable liquid crystal material as defined above by polymerisation or polymeranaloguous reaction. Particularly preferred are SCLCPs obtained from one or more monomers according to formula I wherein one or both of R⁹ and R¹⁰ are a polymerisable or reactive group, or from a polymerisable mixture comprising one or more of such monomers of formula I.

[0074] Another aspect of the invention relates to an SCLCP obtained from one or more monomers of formula I wherein one or both of R⁹ and R¹⁰ are a polymerisable group, or from a polymerisable liquid crystal mixture as defined above, by copolymerisation or polymeranaloguous reaction together with one or more additional mesogenic or non-mesogenic comonomers.

[0075] Side chain liquid crystal polymers or copolymers (SCLCPs), in which the semiconducting component is located as a pendant group, separated from a flexible backbone by an aliphatic spacer group, offer the possibility to obtain a highly ordered lamellar like morphology. This structure consists of closely packed conjugated aromatic mesogens, in which very close (typically < 4 Å) pi-pi stacking can occur. This stacking allows intermolecular charge transport to occur more easily, leading to high charge carrier mobilities. SCLCPs are advantageous for specific applications as they can be readily synthesized before processing and then e.g. be processed from solution in an organic solvent. If SCLCPs are used in solutions, they can orient spontaneously when coated onto an appropriate surface and when at their mesophase temperature, which can result in large area, highly ordered domains.

[0076] Polymerisation is preferably carried out by in-situ polymerisation of a coated layer of the material, preferably during fabrication of the electronic or optical device comprising the inventive semiconductor material. In case of liquid crystal materials, these are preferably aligned in their liquid crystal state into homeotropic orientation prior to polymerisation, where the conjugated pi-electron systems are orthogonal to the direction of charge transport. This ensures that the intermolecular distances are minimised and hence then energy required to transport charge between molecules is minimised. The molecules are then polymerised or crosslinked to fix the uniform or entation of the liquid crystal state. Alignment and curing are carried out in the liquid crystal phase or mesophase of the material. This technique is known in the art and is generally described for example in D.J. Broer, et al., Angew. Makromol. Chem. 183, (1990), 45-66 [0077] Alignment of the liquid crystal material can be achieved for example by treatment of the substrate onto which the material is coated, by shearing the material during or after coating, by application of a magnetic or electric field to 30 the coated material, or by the addition of surface-active compounds to the liquid crystal material. Reviews of alignment techniques are given for example by I. Sage in "Thermotropic Liquid Crystals", edited by G. W. Gray, John Wiley & Sons, 1987, pages 75-77, and by T. Uchida and H. Seki in "Liquid Crystals - Applications and Uses Vol. 3", edited by B. Bahadur, World Scientific Publishing, Singapore 1992, pages 1-63. A review of alignment materials and techniques is given by J. Cognard, Mol. Cryst. Liq. Cryst. 78, Supplement 1 (1981), pages 1-77.

25 [0078] Polymerisation takes place by exposure to heat or actinic radiation. Actinic radiation means irradiation with light, like UV light, IR light or visible light, irradiation with X-rays or gamma rays or irradiation with high energy particles, such as ions or electrons. Preferably polymerisation is carried out by UV irradiation at a non-absorbing wavelength. As a source for actinic radiation for example a single UV lamp or a set of UV lamps can be used. When using a high lamp power the curing time can be reduced. Another possible source for actinic radiation is a laser, like e.g. a UV laser, an IR laser or a visible laser.

[0079] Polymerisation is preferably carried out in the presence of an initiator absorbing at the wavelength of the actinic radiation. For example, when polymerising by means of UV light, a photoinitiator can be used that decomposes under UV irradiation to produce free radicals or ions that start the polymerisation reaction. When curing polymerisable materials with acrylate or methacrylate groups, preferably a radical photoinitiator is used, when curing polymerisable materials with vinyl, epoxide and oxetane groups, preferably a cationic photoinitiator is used. It is also possible to use a polymerisation initiator that decomposes when heated to produce free radicals or ions that start the polymerisation. As a photoinitiator for radical polymerisation for example the commercially available Irgacure 651, Irgacure 184, Darocure 1173 or Darocure 4205 (all from Ciba Geigy AG) can be used, whereas in case of cationic photopolymerisation the commercially available UVI 6974 (Union Carbide) can be used.

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[0080] The polymerisable material can additionally comprise one or more other suitable components such as, for example, catalysts, sensitizers, stabilizers, inhibitors, chain-transfer agents, co-reacting monomers, surface-active compounds, lubricating agents, wetting agents, dispersing agents, hydrophobing agents, adhesive agents, flow improvers, defoaming agents, deaerators, diluents, reactive diluents, auxiliaries, colourants, dyes or pigments.

[0081] Mono-, oligo- and polymers comprising one or more groups P-Sp-X can also be copolymerised with polymerisable mesogenic compounds to induce, or, in case of mesogenic materials of formula I, enhance liquid crystal phase behaviour. Polymerisable mesogenic compounds that are suitable as comonomers are known in prior art and disclosed for example in WO 93/22397: EP 0.261.712: DE 195.04.224: WO 95/22586 and WO 97/00600.

[0082] SCLCPs can be prepared from the polymerisable compounds or mixtures according to the invention by the

methods described above, or by conventional polymerisation techniques which are known to those skilled in the art, including for example radicalic, anionic or cationic chain polymerisation, polyaddition or polycondensation. Polymerisation can be carried out for example as polymerisation in solution, without the need of coating and prior alignment, or polymerisation in situ. It is also possible to form SCLCPs by grafting compounds according to the invention with a suitable reactive group, or mixtures thereof, to presynthesized isotropic or anisotropic polymer backbones in a polymeranaloguous reaction. For example, compounds with a terminal hydroxy group can be attached to polymer backbones with lateral carboxylic acid or ester groups, compounds with terminal isocyanate groups can be added to backbones with free hydroxy groups, compounds with terminal vinyl or vinyloxy groups can be added e.g. to polysiloxane backbones with Si-H groups. It is also possible to form SCLCPs by copolymerisation or polymeranaloguous reaction from the inventive compounds together with conventional mesogenic or non mesogenic comonomers. Suitable comonomers are known to those skilled in the art. In principle it is possible to use all conventional comonomers known in the art that carry a reactive or polymerisable group capable of undergoing the desired polymer-forming reaction, like for example a polymerisable or reactive group P as defined above. Typical mesogenic comonomers are for example those mentioned in WO 93/22397; EP 0,261,712; DE 195,04,224; WO 95/22586 and WO 97/00600. Typical non mesogenic comonomers are for example alkyl mono- or diacrylates or alkyl mono- or dimethacrylates with alkyl groups of 1 to 20 C atoms, like methyl acrylate or methyl methacrylate, trimethylpropane trimethacrylate or pentaerythritol tetraacrylate. [0083] The mono-, oligo- and polymers of the present invention are useful as optical, electronic and semiconductor materials, in particular as charge transport materials in field effect transistors (FETs) e.g. as components of integrated circuitry, ID tags or TFT applications. Alternatively, they may be used in organic light emitting diodes (OLEDs) in electroluminescent display applications or as backlight of e.g. liquid crystal displays, as photovoltaics or sensor materials, for electrophotographic recording, and for other semiconductor applications.

[0084] Especially the oligomers and polymers according to the invention show advantageous solubility properties which allow production processes using solutions of these compounds. Thus films, including layers and coatings, may be generated by low cost production techniques e.g. spin coating. Suitable solvents or solvent mixtures comprise alkanes and/ or aromatics, especially their fluorinated derivatives.

[0085] The materials of the present invention are useful as optical, electronic and semiconductor materials, in particular as charge transport materials in field effect transistors (FETs), as photovoltaics or sensor materials, for electrophotographic recording, and for other semiconductor applications. Such FETs, where an organic semiconductive material is arranged as a film between a gate-dielectric and a drain and a source electrode, are generally known e.g. from US 5,892,244, WO 00/79617, US 5,998,804, and from the references cited in the background and prior art chapter and listed below. Due to the advantages, like low cost production using the solubility properties of the compounds according to the invention and thus the processibility of large surfaces, preferred applications of these FETs are such as integrated circuitry, TFT-displays and security applications.

[0086] In security applications, field effect transistors and other devices with semiconductive materials, like transistors or diodes, may be used for ID tags or security markings to authenticate and prevent counterfeiting of documents of value like banknotes, credit cards or ID cards, national ID documents, licenses or any product with money value, like stamps, tickets, shares, cheques etc..

[0087] Alternatively, the mono-, oligo- and polymers according to the invention may be used in organic light emitting devices or diodes (OLEDs), e.g. in display applications or as backlight of e.g. liquid crystal displays. Common OLEDs are realized using multilayer structures. An emission layer is generally sandwiched between one or more electron-transport and/ or hole-transport layers. By applying an electric voltage electrons and holes as charge carriers move towards the emission layer where their recombination leads to the excitation and hence luminescence of the lumophor units contained in the emission layer. The inventive compounds, materials and films may be employed in one or more of the charge transport layers and/or in the emission layer, corresponding to their electrical and/ or optical properties. Furthermore their use within the emission layer is especially advantageous, if the compounds, materials and films according to the invention show electroluminescent properties themselves or comprise electroluminescent groups or compounds. The selection, characterization as well as the processing of suitable monomeric, oligomeric and polymeric compounds or materials for the use in OLEDs is generally known by a person skilled in the art, see e.g. Meerholz, Synthetic Materials, 111-112, 2000, 31-34, Alcala, J. Appl. Phys., 88, 2000, 7124-7128 and the literature cited therein. [0088] According to another use, the inventive compounds, materials or films, especially those which show photoluminescent properties, may be employed as materials of light sources, e.g. of display devices such as described in EP 0 889 350 A1 or by C. Weder et al., Science, 279, 1998, 835-837.

Examples

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Example 1

[0089] 2,7-Dibromofluorenone (1) was prepared as described below:

[0090] 2,7-Dibromofluorene (20.00 g, 61.72 mmol), potassium permanganate (31.61 g, 200.0 mmol) and copper(II) sulphate pentahydrate (49.94 g, 200.0 mmol) were ground together to afford a fine powder. The powder was heated at 175-180°C for 6 h. After cooling to room temperature, tetrahydrofuran (1 L) was added and the mixture was sonicated for 30 minutes before being filtered through celite. The solvent was removed under reduced pressure to afford a crude product, which was triturated with hot methanol (300 mL) and filtered before being dried under reduced pressure to afford 2,7-dibromofluorenone (1) (17.94 g, 86%) as a yellow solid, purity 100% (GC): ¹H and ¹³C NMR spectra as expected; M+ = 338 (t).

[0091] 2,7-Dibromo-9-dibromomethylenefluorene (2) was prepared as described below:

[0092] Triphenylphosphine (34.89 g, 133.0 mmol) was added to a solution of 2,7-dibromofluorenone (17.94 g, 53.08 mmol) in anhydrous tetrahydrofuran (550 mL) under nitrogen and the reaction mixture was heated at just below reflux with stirring. A solution of carbon tetrabromide (35.16 g, 106.0 mmol) in anhydrous tetrahydrofuran (150 mL) was added dropwise over 1.5 h, and the reaction mixture was heated at reflux for 17 h with stirring. After cooling to room temperature, the solvent was removed under reduced pressure and dichloromethane was added forming a slurry. The solid was filtered off and washed with dichloromethane. Recrystallisation of the solid from dichloromethane afforded 2,7-dibromo-9-dibromomethylene-fluorene (2) (15.30 g, 58%) as a bright orange powder, purity 100% (GC): v_{max} (KBr, cm⁻¹) 3115, 3066, 1605, 1566, 1547, 1450, 1399, 1264, 1073; ¹H and ¹³C NMR spectra as expected; M+ = 494 (pent). [0093] 2,7-Dibromo-9-(bis-heptylsulfanyl-methylene)fluorene (3) was prepared as described below:

[0094] A 60% dispersion of sodium hydride in mineral oil (3.45 g, 86.25 mmol) was added under a heavy flow of nitrogen to anhydrous toluene (1 L). 1-Heptanethiol (14.65g, 17.0 mL, 110.7 mmol) was added *via* syringe. Once effervescence stopped, 2,7-dibromo-9-dibromomethylene-fluorene (2) (18.50 g, 37.46 mmol) was added followed by 2,2'-bipyridyl (0.29 g, 1.87 mmol) and nickel(II) chloride dimethoxyethane adduct (0.41 g, 1.87 mmol). The reaction was stirred overnight at reflux. After cooling to room temperature, the reaction mixture was washed with 2M aqueous sodium hydroxide (2 x 100 mL), 5% aqueous hydrochloric acid (2 x 100 mL), water (200 mL), and brine (200ml) before being dried over sodium sulphate and evaporated to dryness. Excess 1-heptanethiol was removed *via* Kugelrohr dis-

tillation. The crude product was purified by flash chromatography (eluent: petrol 40-60) followed by_recrystallisation from iso-hexane to afford 2,7-dibromo-9-(bis-heptylsulfanyl-methylene)-fluorene (3) (16.76g, 75%) as a bright yellow solid, purity 100% (GC): v_{max} (KBr, cm⁻¹) 3068, 2949, 2920, 2851, 1588, 1559, 1513, 1443, 1396, 1330; δ_{H} (CDCl₃, 300 MHz) 9.09 (2H, s), 7.53 (2H, d, $^3J_{HH}$ = 6.0 Hz), 7.43 (2H, d, $^3J_{HH}$ = 6.0 Hz), 3.04 (4H, t, $^3J_{HH}$ = 7.5 Hz) 1.70 (4H, m), 1.43 (4H, m), 1.26 (12H, m), 0.86 (6H, m); δ_{C} (CDCl₃, 75 MHz) 145.5, 139.7, 137.6, 136.1, 130.3, 129.5, 121.1, 120.3, 36.4, 31.7, 30.1, 28.9, 22.6, 14.1; M+ = 596 (t).

Example 2

10 [0095] 2,7-Dibromo-9-(bis-pentylsulfanyl-methylene)fluorene (4) was prepared by a procedure as described in example 1 (63%):

 $\delta_{\text{H}}(\text{CDCl}_3, 300 \text{ MHz})$ 9.1 (2H, s), 7.50 (2H, d), 7.40 (2H, d), 3.05 (4H) 1.65 (4H, m), 1.5-1.3 (8H, m), 0.85 (6H, t); δ_{C} (CDCl $_3$, 75 MHz) 145.4, 139.7, 137.5, 136.1, 130.28 (ArCH), 129.4 (ArCH), 121.0, 120.3 (ArCH), 36.3, 31.0, 29.8, 22.3, 14.0; M+ = 540 (t).

Example 3

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[0096] 2-Bromo-9-(bis-methylsulfanyl-methylene)fluorene (5) was prepared as described in example 2 using meth-30 yliodide as the alkylating agent. (76%). M⁺ = 350 (d). ¹H NMR displayed the expected signals.

Example 4

45 [0097] Poly[9-(bis-heptylsulfanyl-methylene)-fluorene-2,7'-diyl] (6) was prepared as described below:

[0098] A schlenk tube was charged with bis(1,5-cyclooctadiene)nickel(0) (2.045 g, 7.434 mmol), 2,2'-bipyridyl (1.161

g, 7.434 mmol) and 2,7-dibromo-9-(bis-heptylsulfanyl-methylene)-fluorene (3) (3.686 g, 6.178 mmol) under nitrogen. Anhydrous N,N-dimethylomamide (30 mL), anhydrous toluene (15 mL) and 1,5-cyclooctadiene (0.705 g, 0.8 mL, 6.522 mmol) were added to the schlenk tube via syringe. The reaction mixture was heated at 70°C for 2 days with stirring. After cooling to room temperature, the reaction mixture was added dropwise to methanol (500 mL). The precipitate was filtered off and washed with iso-hexane followed by methanol (via Soxhlet extraction). The precipitate was dissolved in a minimum volume of chloroform and re-precipitated from methanol (500 mL). The polymer was filtered off and dried under reduced pressure to afford poly[9-(bis-heptylsulfanyl-methylene)-fluorene-2,7'-diyl] (6) (1.730 g, 64%) as a dark red solid: mp > 250°C, v_{max} (KBr, cm⁻¹) 3053, 2952, 2923, 2851, 1599, 1553, 1517, 1451, 1403; ¹H and ¹³C NMR as expected; $M_w = 7,500$, $M_n = 3,000$; abs λ_{max} (THF) 347 nm.

Example 5

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[0099] Poly[9-(bis-pentylsulfanyl-methylene)-fluorene-2,7'-diyl] (7) was prepared as described in example 6 (29%): mp > 250°C; 1 H NMR as expected; $M_{\rm w}$ = 7,300, $M_{\rm n}$ = 3,750; abs $\lambda_{\rm max}$ (THF) 350 nm.

Claims

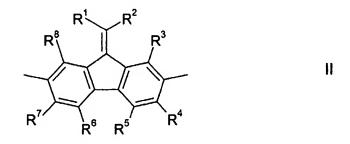
1. Mono-, oligo- and polymers of formula I

$$R^9$$
-[(A)_a-(B)_b-(C)_c]_n-R¹⁰ I

wherein

A and C are independently of each other -CX¹=CX²-, -C≡C-, or optionally substituted arylene or heteroarylene,

X¹ and X² are independently of each other H, F, Cl or CN, B is a group of formula II



R¹ and R² are independently of each other halogen, straight chain, branched or cyclic alkyl with 1 to 20 Catoms, which may be unsubstituted, mono- or polysubstituted by F, Cl, Br, I or CN, it being also possible for one or more non-adjacent CH₂ groups to be replaced, in each case independently from

one another, by -O-, -S-, -NH-, -NR⁰-, -SiR⁰R⁰⁰-, -CO-, -COO-, -OCO-, -OCO-, -SO₂-, -S-CO-, -CO-S-, - CH=CH- or -C≡C- in such a manner that O and/or S atoms are not linked directly to one another, optionally substituted aryl or heteroaryl, or P-Sp-X,

- 5 R3 to R10 independently of each other denote H or have one of the meanings given for R1,
 - R⁰, R⁰⁰ are independently of each other H or alkyl with 1 to 12 C-atoms,
 - P is a polymerisable or reactive group,
 - Sp is a spacer group or a single bond, and
 - X is -O-, -S-, -OCH₂-, -CH₂O-, -CO-, -COO-, -OCO-O-, -CO-NR⁰-, -NR⁰-CO-, -OCH₂-, -CH₂O-, -SCH₂-, -CH₂S-, -CH=CH-COO-, -OOC-CH=CH- or a single bond,
 - a, b, c are independently of each other 0 or 1, with a + b + c > 0, and wherein in at least one recurring unit $[(A)_a(B)_b-(C)_c]$ b is 1, and
 - n is an integer ≥ 1,

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wherein the recurring units [(A)_a-(B)_b-(C)_c] can be identical or different, and with the provisos that

- a) in case n is 1, a and c are 0, R^{3-8} are H, and one of R^1 and R^2 is methyl and the other is methyl, ethyl or phenyl, R^9 and R^{10} are not at the same time Cl or Br, and
- b) A and C are different from 2,7-(4-hexylphenyl)fluorene-9-carbonyl.
- 2. Mono-, oligo- and polymers according to claim 1, wherein n Is an integer from 1 to 5000.
- Mono-, oligo- and polymers according to claim 1 or 2, wherein R¹ to R⁸ are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkynyl, C₁-C₂₀-alkoxy, C₁-C₂₀-thioether, C₁-C₂₀-silyl, C₁-C₂₀-ester, C₁-C₂₀-amino, C₁-C₂₀-fluoroalkyl, or optionally substituted aryl or heteroaryl.
 - 4. Mono-, oligo- and polymers according to claim 3, wherein R¹ and R² are selected from C₁-C₂₀-alkyl that is optionally substituted with one or more fluorine atoms, C₁-C₂₀-alkenyl, C₁-C₂₀-alkynyl, C₁-C₂₀-alkoxy, C₁-C₂₀-thioether, C₁-C₂₀-silyl, C₁-C₂₀-ester, C₁-C₂₀-amino, C₁-C₂₀-fluoroalkyl, or optionally substituted aryl or heteroaryl, and R³ to R³ are H
 - Mono-, oligo- and polymers according to at least one of claims 1 to 4, wherein n is an integer from 1 to 15 and one or both of R⁹ and R¹⁰ denote P-Sp-X.
 - 6. Oligo- and polymers according to at least one of claims 1 to 5, wherein n is an integer from 2 to 5000.
 - 7. Mono-, oligo- and polymers according to at least one of claims 1 to 6, wherein P is selected from CH₂=CW¹-COO-,

- CH₂=CW²-(O)_{k1}-, CH₃-CH=CH-O-, HO-CW²W³-, HS-CW²W³-, HW²N-, HO-CW²W³-NH-, CH₂=CW¹-CO-NH-, CH₂=CH-(COO)_{k1}-Phe-(O)_{k2}-, Phe-CH=CH-, HOOC-, OCN- and W⁴W⁵W⁶Si-, with W¹ being H, Cl, CN, phenyl or alkyl with 1 to 5 C-atoms, in particular H, Cl or CH₃, W² and W³ being independently of each other H or alkyl with 1 to 5 C-atoms, in particular methyl, ethyl or n-propyl, W⁴, W5 and W⁶ being independently of each other Cl, oxaalkyl or oxacarbonylalkyl with 1 to 5 C-atoms, Phe being 1,4-phenylene and k₁ and k₂ being independently of each other 0 or 1.
- 8. Mono-, oligo- and polymers according to at least one of claims 1 to 7, selected from the following formulae

$$\begin{array}{c|c}
R^{1} & R^{2} \\
R^{9} & R^{10}
\end{array}$$
la

$$\begin{array}{c|c}
R^{8} & R^{2} \\
R^{9} & R^{3} \\
R^{7} & R^{8} & R^{5}
\end{array}$$
Ib

$$\begin{array}{c|c}
R^{8} & R^{2} \\
R^{9} & Ar \rightarrow_{n} R^{10}
\end{array}$$
Ih

- wherein R¹ to R¹⁰ have independently of each other one of the meanings of formula I, Ar is arylene or heteroarylene, and n is an integer from 1 to 5000.
 - 9. Polymerisable liquid crystal material comprising one or more mono-, oligo- or polymers of at least one of claims 1 to 8 comprising at least one polymerisable group, and optionally comprising one or more further polymerisable compounds, wherein at least one of the polymerisable mono-, oligo- and polymers of claims 1 to 8 and/or the further polymerisable compounds is mesogenic or liquid crystalline.
 - 10. Anisotropic polymer film with charge transport properties obtainable from a polymerisable liquid crystal material according to claim 9 that is aligned in its liquid crystal phase into macroscopically uniform orientation and polymerised or crosslinked to fix the oriented state.
 - 11. Side chain liquid crystal polymer obtained by polymerisation of one or more mono- or oligomers or a polymerisable material according to claims 1 to 9 or by grafting one or more mono- or oligomers or a polymerisable material according to claims 1 to 9 to a polymer backbone in a polymeranaloguous reaction, optionally with one or more additional mesogenic or non-mesogenic comonomers.
 - 12. Use of the mono-, oligo- and polymers, polymerisable material and polymer of claims 1 to 11 as semiconductors or charge transport materials, in particular in optical, electrooptical or electronic devices, like for example components of integrated circuitry, field effect transistors (FET) for example as thin film transistors in flat panel display applications or for Radio Frequency Identification (RFID) tags, or in semiconducting components for organic light emitting diode (OLED) applications such as electroluminescent displays or backlights of e.g. liquid crystal displays, for photovoltaic or sensor devices, as electrode materials in batteries, as photoconductors and for electrophotographic applications like electrophotographic recording.
- 40 13. Field effect transistor, for example as a component of integrated circuitry, as a thin film transistor in flat panel display applications, or in a Radio Frequency Identification (RFID) tag, comprising one or more mono-, oligo- or polymers according to the invention comprising one or more mono-, oligo- or polymers, polymerisable material or polymer of claims 1 to 11.
- 45 14. Security marking or device comprising comprising one or more mono-, oligo- or polymers, a polymerisable material or a polymer of claims 1 to 11, or a FET or RFID tag according to claim 13.
 - 15. Mono-, oligo- and polymers, a material or polymer according to at least one of claims 1 to 11, which are oxidatively or reductively doped to form conducting ionic species.
 - 16. Charge injection layer, planarising layer, antistatic film or conducting substrate or pattern for electronic applications or flat panel displays, comprising mono-, oligo- or polymers, a material or polymer film according to claim 15.

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- (54) Mono-, oligo- and polyalkylidenefluorenes and their use as charge transport materials
- (57) The invention relates to new conjugated mono, oligo- and polyalkylidenefluorenes. The invention further relates to methods for their preparation, their use as semiconductors or charge transport materials in optical, electrooptical or electronic devices including field

effect transistors, electroluminescent, photovoltaic and sensor devices. The invention further relates to field effect transistors and semiconducting components comprising the new mono-, oligo- and polymers.



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